Diode Semiconductor Device - Page 1 of 1



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Inc	losure Material:
Me	tal
Ov	erall Length:
0.0	91 inches
Те	rminal Length:
0.0	62 inches
Ov	erall Diameter:
0.1	21 inches
Мс	unting Method:
Те	rminal
Fe	atures Provided:
He	rmetically sealed case
Se	miconductor Material:
Sili	con
Cu	rrent Rating Per Characteristic:
6.0	0 amperes repetitive peak forward current
Ро	wer Rating Per Characteristic:
10	0 watts total power dissipation
Ма	ximum Operating Tempurature Per Measurement Point:
17	5.0 degrees celsius junction
Те	rminal Type And Quantity:
2 f	errule
Sh	elf Life:
N/a	a de la constante de
Un	it Of Measure:
De	militarization:
No	
Fii	g:
A1	10a0